

## PAPER

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# Photoelectrochemical performance of a nanostructured BiVO<sub>4</sub>/NiOOH/FeOOH–Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> tandem cell for unassisted solar water splitting†

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An unassisted solar water splitting tandem cell is fabricated using FeOOH/NiOOH-coated BiVO<sub>4</sub> nanostructures as a photoanode and a TiO<sub>2</sub>-protected heterojunction Cu<sub>2</sub>O/CuO thin film as a photocathode. The individual photoelectrochemical (PEC) performance of the nanostructured BiVO<sub>4</sub>/NiOOH/FeOOH photoanode produces a photocurrent of 2.05 mA cm<sup>−2</sup> at 1.23 V vs. RHE, while the Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> photocathode delivers −1.61 mA cm<sup>−2</sup> at 0 V vs. RHE under an AM 1.5 filtered illumination of 100 mW cm<sup>−2</sup>. The operating point of tandem cell photocurrent is found to be 0.273 mA cm<sup>−2</sup> at 0.56 V vs. RHE. From two-electrode linear sweep voltammetry, the tandem cell (BiVO<sub>4</sub>/NiOOH/FeOOH–Cu<sub>2</sub>O/CuO/TiO<sub>2</sub>) delivers an unassisted current density of 0.201 mA cm<sup>−2</sup> at 0 V. The chronoamperometry test further demonstrates the stable nature of the tandem cell, which retains a current density of 0.187 mA cm<sup>−2</sup> during a testing duration of 3000 seconds. The proposed tandem cell provides optimized solutions to designing a cost-effective and stable solar water splitting system for the fulfillment of the future energy needs.

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## 1. Introduction

The production of solar hydrogen using semiconductor photoelectrode materials is considered a potential strategy to provide clean and green energy with zero carbon footprint without substantially modifying the existing infrastructure. A single-electrode semiconductor photoelectrochemical (PEC) system has yet to find a way to achieve a practical efficiency of 10% since the pioneering work of Fujishima and Honda in 1972.<sup>1</sup> The tandem integration of solar cells along with the PEC system<sup>2</sup> is advantageous when state-of-the-art solar cells are constructed with semiconductor materials for solar water splitting. Recent research studies examined such an approach by combining photovoltaic devices, such as dye sensitized solar cells<sup>3</sup> and perovskite solar cells,<sup>4</sup> with a PEC device consisting of a single semiconductor electrode and found that it produces a higher solar-to-hydrogen (STH) conversion efficiency (13.8%).<sup>5</sup> However, the overall complexity of the system and photo-corrosion of narrow bandgap semiconductors are critical issues

in commercializing such approaches. Compared to the PV-integrated PEC approach, a tandem PEC cell consisting of an n-type photoanode and p-type photocathode<sup>6</sup> is a viable approach in terms of feasibility and practicality. Certain basic requirements should be met for the construction of efficient tandem PEC cells. First, the bandgap of semiconductors used in tandem cells should be complementary to each other and should be chosen as per the proposed contour plot<sup>7</sup> to achieve the maximum theoretical efficiency. The implementation of complementary bandgap semiconductors enables harvesting a significant portion of the incoming solar spectrum.<sup>8</sup> Second, the valence band edge position of the semiconductor should be more positive than the water oxidation potential (1.23 V vs. RHE at pH = 0) for photoanodes, and the conduction band edge of the semiconductor should be more negative than the water reduction potential (0 V vs. RHE at pH = 0) for photocathodes.<sup>9</sup> The difference in the Fermi level of the photoanode and photocathode determines the bias required for solar water splitting.

Among various semiconductors, bandgap tunable ternary metal oxides are suitable candidates for photoanodes.<sup>10</sup> BiVO<sub>4</sub> fulfills several requirements of being an efficient photoanode in a tandem cell. With a bandgap of 2.4 eV (ref. 11) and favorable band edge positions, BiVO<sub>4</sub> can be used for the water oxidation reaction. However, BiVO<sub>4</sub> suffers from surface recombination, a high onset potential and poor water oxidation kinetics.<sup>12</sup> These hurdles significantly reduce the current density of BiVO<sub>4</sub>

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compared to the theoretical current density of  $7.5 \text{ mA cm}^{-2}$ .<sup>13</sup> Approaches, such as the addition of dopants, heterojunction formation, incorporating an interlayer<sup>14</sup> and increasing the surface area by morphology control, can improve its PEC properties.  $\text{BiVO}_4$  porous nanostructures help in aiding the charge separation and surface-to-volume ratio due to its hollow network. Sutripto Majumder *et al.*<sup>15</sup> studied the effect of  $\text{ZnFe}_2\text{O}_4$  on  $\text{BiVO}_4$  nanostructure photoanodes, which produced a photocurrent density of  $0.73 \text{ mA cm}^{-2}$  at  $1.23 \text{ V vs. RHE}$ . This photocurrent density value is higher than that for the thin film counterpart.<sup>16</sup> In order to obtain unassisted tandem cell operation, the onset potential could be reduced or the current density should be increased in the lower applied potential region.<sup>17</sup> To achieve this, the co-catalyst can be loaded onto the surface of the photoanode. The loading of the oxygen evolution reaction (OER) co-catalysts provides active sites for the interfacial reaction, in addition to reducing the overpotential. The OER catalysts also improve the stability by effectively transferring the photogenerated carriers from the bulk of the photoanode to the surface due to the favorable band alignment. Several inexpensive transition metal oxyhydroxides such as  $\text{FeOOH}$  and  $\text{NiOOH}$  have been extensively used as co-catalysts for the  $\text{BiVO}_4$  photoanode. Dong Ki Lee *et al.*<sup>18</sup> analyzed the effect of  $\text{BiVO}_4$  using dual oxyhydroxides, which produced a remarkable current density of  $\sim 5 \text{ mA cm}^{-2}$  at  $1.23 \text{ V vs. RHE}$ .

Among various photocathode materials, cuprous oxide ( $\text{Cu}_2\text{O}$ ) fulfills many requirements, such as a narrow bandgap, ease of fabrication and suitable band edge positions. The narrow bandgap of  $2.1 \text{ eV}$  is capable of boosting the efficiency of the tandem cells. On the other hand,  $\text{Cu}_2\text{O}$  suffers from higher recombination, owing to the short diffusion length of the minority charge carriers and photocorrosion in the presence of an aqueous medium. The film thickness of  $1 \mu\text{m}$  is required for effective absorption, but the achieved diffusion length ranges from  $20$  to  $200 \text{ nm}$  based on the synthesis process.<sup>19</sup> Charge separation is also a crucial parameter to maximize the performance of the photocathode in the tandem cell. Cupric oxide ( $\text{CuO}$ ) is comparatively more stable than  $\text{Cu}_2\text{O}$ . Appropriate band matching of  $\text{Cu}_2\text{O}$  and  $\text{CuO}$  boosts the performance of the photocathode.<sup>20</sup> The heterojunction of  $\text{Cu}_2\text{O}$  and  $\text{CuO}$  showed promising PEC performance in terms of the stability, charge separation and efficiency. Pan Wang *et al.*<sup>21</sup> constructed a Pt-loaded  $\text{Cu}_2\text{O}/\text{CuO}$  heterojunction photocathode, which produced a current density of  $-1.99 \text{ mA cm}^{-2}$  at the water reduction potential. The increase in the current density was attributed to improved charge separation due to *in situ* formation of the  $\text{CuO}$  layer. The addition of the  $\text{CuO}$  layer reduced the charge transfer barrier at the surface. To prevent photocorrosion, various protective layers, such as  $\text{TiO}_2$  and carbon,<sup>22</sup> can be deposited. Yuanbin Wang *et al.* demonstrated a  $\text{TiO}_2$  protective layer on the  $\text{Cu}_2\text{O}$  photocathode using the atomic layer deposition method (ALD), which generated a current density of  $-3.71 \text{ mA cm}^{-2}$  at  $0 \text{ V vs. RHE}$ . A band alignment of  $\text{Cu}_2\text{O}/\text{CuO}$  provides stable protection with better charge separation and transport.<sup>23</sup>

In this work, we constructed a model tandem system consisting of a nanostructured  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  photoanode

and  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  photocathode towards enhancing the PEC performance of the cell for unassisted solar water splitting. The novelty of this tandem cell is the employment of earth-abundant oxide semiconductor materials, which is chemically more stable than non-oxide elemental semiconductors. The combination of the photoelectrodes and inexpensive co-catalysts has rarely been reported in the literature in terms of the nanostructured photoanode and heterojunction photocathodes with a protective layer. We anticipate that the tandem cell will simultaneously improve the optical absorption, charge transport, and interfacial charge transfer for unbiased solar water splitting. The nanostructured photoanode enhanced the surface area, and the  $\text{NiOOH}/\text{FeOOH}$  dual layer co-catalysts minimized the overpotential and improved the charge transfer resistance. The performance of the photocathode was improved through heterojunction formation with stable  $\text{CuO}$  on  $\text{Cu}_2\text{O}$ . The photocathode was further deposited by a spin-coated  $\text{TiO}_2$  layer to protect it from photocorrosion. The constructed  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  photoanode- $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  photocathode produced a positive current density in the unassisted PEC tests. The non-zero operating points provided the possibility of the operation of a tandem cell without an external bias.

## 2. Experimental methods

### 2.1 Materials

Bismuth nitrate pentahydrate, *p*-benzoquinone, copper sulphate pentahydrate, FTO substrates, iron sulphate, and potassium iodide were purchased from Sigma Aldrich. Lactic acid and vanadyl acetylacetonate were purchased from Avra chemicals. Nickel sulphate hexahydrate and sodium hydroxide were purchased from SDFCL limited. Sodium sulphate was purchased from Alfa Aesar. All of the chemicals used in the study were of analytical grade, and used without further purification.

### 2.2 Preparation of $\text{BiVO}_4$ nanostructures

FTO substrates were separately ultrasonically cleaned with acetone, isopropanol and ethanol. The  $\text{BiVO}_4$  photoanodes were prepared through the electrodeposition of  $\text{BiOI}$  on FTO substrates, followed by the conversion of  $\text{BiOI}$  into  $\text{BiVO}_4$  using the drop-casting of a vanadium precursor solution and subsequent annealing in air.<sup>24</sup>

**2.2.1 Electrochemical deposition of  $\text{BiOI}$ .** The electrodeposition of bismuth oxyiodide ( $\text{BiOI}$ ) was performed in a typical three-electrode setup, in which the FTO substrate,  $\text{Ag}/\text{AgCl}$  (saturated KCl) and platinum (Pt) wire were used as the working, reference and counter electrodes, respectively. FTO substrates were ultrasonically cleaned using acetone, isopropanol and ethanol sequentially. The plating solution consists of  $15 \text{ mM}$  of bismuth nitrate pentahydrate,  $400 \text{ mM}$  of potassium iodide, and  $30 \text{ mM}$  lactic acid. The precursors were rigorously stirred to make a clear homogenous solution, and the pH was adjusted to  $1.8$  by adding dilute nitric acid. First,  $46 \text{ mM}$  of *p*-benzoquinone was mixed in  $20 \text{ mL}$  ethanol. Then, the *p*-benzoquinone solution was added to the bismuth nitrate



solution slowly because the sudden addition can cause precipitation of BiOI. The plating solution was stirred for 10 minutes, and the pH was adjusted to 3.4 using dilute nitric acid. The electrochemical deposition of BiOI on the FTO substrates was carried out by applying a constant potential of  $-0.3$  V vs. Ag/AgCl for 20 seconds to increase the nucleation density, followed by applying a constant potential of  $-0.1$  V vs. Ag/AgCl for various time periods (2.5, 5, 7.5 and 10 minutes) to obtain an optimum coating. Finally, BiOI films were rinsed with DI water and dried at room temperature.

**2.2.2 Conversion of BiOI into BiVO<sub>4</sub> photoanodes.** After the electrodeposition of BiOI, the substrates were drop-casted with 200 mM of vanadyl acetylacetonate in dimethyl sulphoxide (DMSO). The substrates were subsequently transferred to a box furnace for thermal treatment at 450 °C for 2 hours in air. After formation of the BiVO<sub>4</sub> nanostructures, the excess V<sub>2</sub>O<sub>5</sub> formed during the thermal treatment was removed by soaking the BiVO<sub>4</sub> photoanode in 1 M NaOH solution for 30 minutes with stirring at 200 rpm. After this process, the BiVO<sub>4</sub> photoanodes were rinsed with a copious amount of DI water and dried at room temperature.

### 2.3 Deposition of FeOOH and NiOOH co-catalysts

The dual co-catalysts were deposited using an electrodeposition method.<sup>25,26</sup> The electrodeposition procedure was carried out in a three-electrode system, in which the BiVO<sub>4</sub> photoanode, Ag/AgCl saturated KCl, and Pt wire were the working electrode, reference electrode, and counter electrode, respectively. Briefly, 0.1 M of iron sulphate solution was prepared and a constant potential of 1.2 V was applied for 5 minutes. The photoanode was rinsed with DI water and dried at room temperature. Similarly, for NiOOH deposition, 0.1 M nickel sulphate solution was prepared and a constant potential of 1.2 V was applied for 5 minutes. Finally, the photoanode was rinsed with DI water and dried at room temperature.

### 2.4 Preparation of the Cu<sub>2</sub>O and Cu<sub>2</sub>O/CuO photocathodes

The Cu<sub>2</sub>O photocathode was prepared using an electrodeposition method.<sup>27</sup> The Cu<sub>2</sub>O plating solution consisted of 0.4 M copper sulphate pentahydrate in 3 M lactic acid. A constant potential of  $-0.4$  V vs. Ag/AgCl was applied to deposit Cu<sub>2</sub>O on the FTO substrate for an hour. Finally, Cu<sub>2</sub>O deposited on the FTO substrates was rinsed with a copious amount of DI water and dried at room temperature.

For the *in situ* growth of CuO on Cu<sub>2</sub>O, the prepared Cu<sub>2</sub>O photocathode was annealed at 300 °C, 400 °C and 500 °C for 30 minutes in an air environment using a muffle furnace.<sup>28</sup>

### 2.5 Preparation of the TiO<sub>2</sub> protective layer

The deposition of TiO<sub>2</sub> was performed using a spin-coating technique.<sup>29</sup> The TiO<sub>2</sub> precursor sol was prepared by mixing titanium isopropoxide in isopropanol (1 : 50 volume ratio). The prepared sol was spin-coated at 1000 rpm for 30 seconds. The TiO<sub>2</sub>-coated Cu<sub>2</sub>O/CuO photocathode (Cu<sub>2</sub>O/CuO/TiO<sub>2</sub>) was annealed at 200 °C for 1 hour in ambient air.

## 2.6 Material characterization

The structural characterization was performed using an X-ray diffractometer, D8 Advanced, Bruker with Cu-K $\alpha$  radiation ( $\lambda = 1.5418$  Å). Vibrational characterization was carried out using the Raman microscope, Horiba XploRA™ plus with the 532 nm green laser as a source (25% laser power). The morphology of the photoanode was analysed using a field emission scanning electron microscope (FESEM), FEI Quanta 250 FEG. Optical characterization was carried out using a UV-vis spectrometer, Specord Plus in the visible range.

## 2.7 Photoelectrochemical characterization

All of the photoelectrochemical (PEC) characterization was carried out in a 3-electrode setup with the photoanode/photocathode as the working electrode, Ag/AgCl saturated KCl as the reference electrode, and Pt wire as the counter electrode. The PEC characterization was recorded in the AMETEK PARSTAT electrochemical workstation. The illumination source was 300 W ozone-free xenon lamp (Ushio, Japan) from Holmarc, India. The illumination source was adjusted to a power intensity of 100 mW cm<sup>-2</sup> using a Newport AM 1.5 G filter. The active area of all photoanodes/photocathode was 1 cm<sup>2</sup>. All PEC measurements were performed in 0.1 M Na<sub>2</sub>SO<sub>4</sub> (pH 6). The electrolyte was purged with nitrogen gas for 30 minutes prior to the testing. All of the PEC measurements were recorded with backside illumination. Linear sweep voltammetry (LSV), chronoamperometry (*j* vs. *t*), and electrochemical impedance spectroscopy (EIS) and Mott-Schottky analysis were performed to characterize the PEC performance of the photoelectrodes. LSV scans were performed at the scan rate of 20 mV s<sup>-1</sup>. Current vs. time (*j* vs. *t*) measurements were performed at 1.23 V vs. RHE and 0 V vs. RHE for the photoanodes and photocathodes, respectively. EIS was performed in the frequency range of 10<sup>5</sup> Hz to 1 Hz using an AC signal with 10 mV amplitude. The Mott-Schottky plot was obtained at a scan range near the reported flat band potential. The potential of the working electrode was converted to a reversible hydrogen electrode (RHE) using the formula,  $E_{\text{RHE}} = E_{\text{Ag/AgCl}} + 0.059 \times \text{pH} + E_{\text{Ag/AgCl}}^{\circ}$ , where  $E_{\text{Ag/AgCl}}^{\circ}$  is the standard potential of the Ag/AgCl saturated KCl reference electrode, which is 0.197 V. All of the potential in the PEC measurement was reported in the RHE scale.

## 2.8 Tandem cell PEC measurements

A tandem PEC cell was constructed with BiVO<sub>4</sub> nanostructure photoanodes as the top cell and Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> as the bottom cell. The tandem measurements were performed in 0.1 M Na<sub>2</sub>SO<sub>4</sub> (pH 6) electrolyte. The electrolyte was purged with nitrogen for 30 minutes prior to the experiments. The active area of the photoanode/photocathode was 1 cm<sup>2</sup>. Electrochemical analysis, such as linear sweep voltammetry (LSV) and unassisted stability tests (*j* vs. *t*), was performed.

# 3. Results and discussion

## 3.1 Characterization of the photoelectrode materials

Fig. 1(a) and (b) shows the FESEM micrograph of the BiVO<sub>4</sub> nanostructured photoanodes with and without co-catalysts.





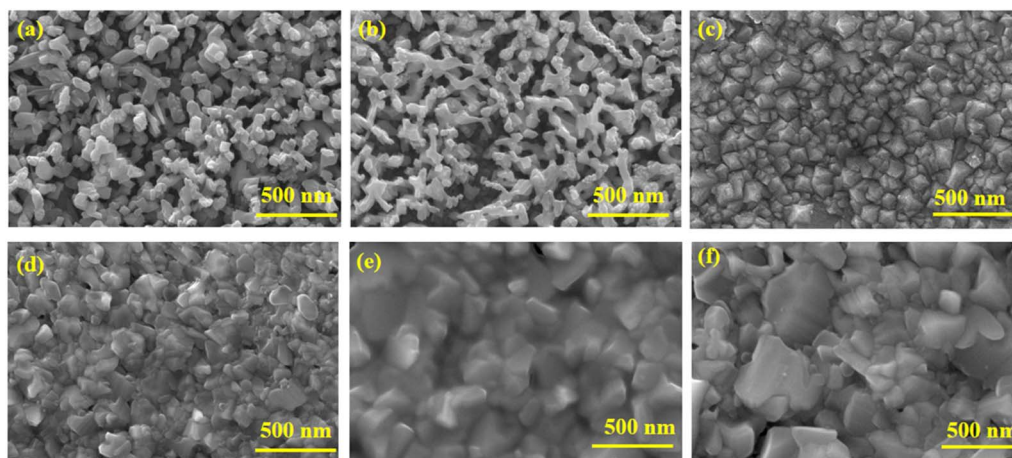


Fig. 1 FESEM image of (a)  $\text{BiVO}_4$ , (b)  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  nanostructured photoanodes, (c) pure  $\text{Cu}_2\text{O}$ , (d)  $\text{Cu}_2\text{O}/\text{CuO}$ , (e)  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  and (f)  $\text{CuO}$  photocathode.

$\text{BiVO}_4$  exhibited a 3D porous network that was formed by small nanoworm-like particles. No significant changes in the morphology was observed after the deposition of  $\text{NiOOH}$  and  $\text{FeOOH}$ . Nevertheless, the co-catalyst deposition was confirmed by EDAX elemental analysis (see ESI, Fig. S2†). The electro-deposited  $\text{Cu}_2\text{O}$  in Fig. 1(c) exhibits a dense compact structure. After annealing, the top layer  $\text{Cu}_2\text{O}$  was converted into  $\text{CuO}$ , and its morphology revealed a slightly bigger dense structure (Fig. 1(f)). As the annealing time (45 minutes) was increased, the  $\text{Cu}_2\text{O}$  layers became completely converted to  $\text{CuO}$ . Hence, the annealing time was limited to 30 minutes to obtain an optimum  $\text{Cu}_2\text{O}/\text{CuO}$  heterojunction, as shown in Fig. 1(d). The cross-sectional FESEM micrograph of the  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  nanostructures ( $2.9 \mu\text{m}$  thick) and  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  ( $1.176 \mu\text{m}$  thick) are shown in Fig. S1 (a) and (b) in the ESI,† respectively. Fig. 1(e) shows the protective layer coating of  $\text{TiO}_2$  on  $\text{Cu}_2\text{O}$ . It was observed that  $\text{TiO}_2$  was conformally coated on top of  $\text{Cu}_2\text{O}/\text{CuO}$  (Fig. 1(e)). The corresponding EDS mapping of the  $\text{BiVO}_4$  nanostructure photoanodes and  $\text{Cu}_2\text{O}$  photocathodes are shown in Fig. S2 and S3 in the ESI,† respectively.

X-Ray Diffraction (XRD) was used to analyze the crystallinity of the photoelectrodes. The XRD pattern of  $\text{BiVO}_4$  and the modified  $\text{BiVO}_4$  photoanodes are shown in Fig. 2(a). The peaks at  $18.9^\circ$  and  $28.9^\circ$  confirmed the presence of the monoclinic scheelite structures of  $\text{BiVO}_4$ . The obtained diffraction peaks are well indexed with JCPDS card no. 14-06888.<sup>30</sup> The peaks of the FTO substrate were denoted as ‘\*’ since some of the uncoated areas of the substrate were also exposed during the characterization. The remaining XRD peaks in Fig. 2(a) indicated the formation of monoclinic  $\text{BiVO}_4$ . No diffraction peaks were obtained for  $\text{FeOOH}$  and  $\text{NiOOH}$  because of the low content and the amorphous nature of the co-catalysts. The XRD patterns of  $\text{Cu}_2\text{O}$ ,  $\text{Cu}_2\text{O}/\text{CuO}$  and  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  are shown in Fig. 2(b). The obtained peaks at  $29.8^\circ$  and  $38^\circ$  are attributed to the formation of cubic  $\text{Cu}_2\text{O}$ . Annealing of the  $\text{Cu}_2\text{O}$  film in air at  $400^\circ\text{C}$  initiated the formation of  $\text{CuO}$ . The formation of  $\text{CuO}$  was confirmed by the peaks at  $35.5^\circ$  (002). The annealing duration of 30 minutes indicated a successful formation of  $\text{Cu}_2\text{O}$  to  $\text{CuO}$ . The XRD pattern obtained with a mixture of  $\text{Cu}_2\text{O}$  and  $\text{CuO}$  reflects the formation of cubic  $\text{CuO}$  (indicated in

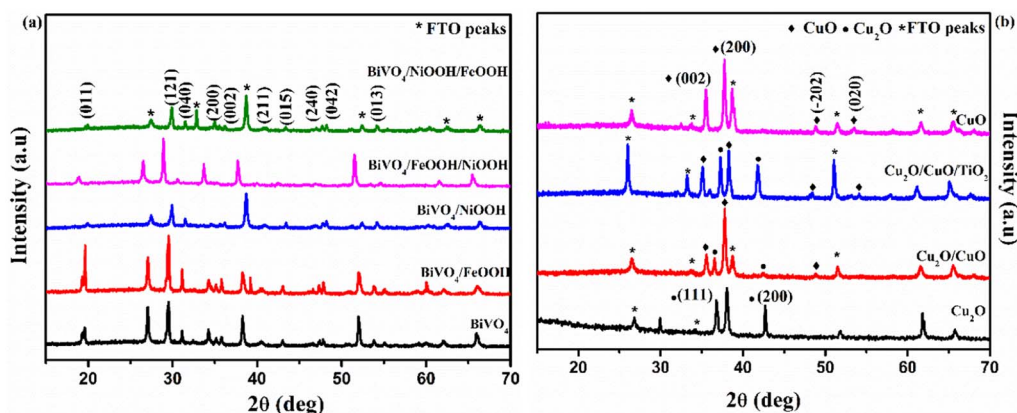


Fig. 2 XRD pattern of (a)  $\text{BiVO}_4$ ,  $\text{BiVO}_4/\text{FeOOH}$ ,  $\text{BiVO}_4/\text{NiOOH}$ ,  $\text{BiVO}_4/\text{FeOOH}/\text{NiOOH}$  and  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  nanostructured photoanodes and (b)  $\text{Cu}_2\text{O}$ ,  $\text{Cu}_2\text{O}/\text{CuO}$ ,  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  and  $\text{CuO}$  photocathodes.



Fig. 2(b), blue line pattern). The obtained XRD pattern was well indexed with the JCPDS card no. 03-0898 (ref. 20) for  $\text{Cu}_2\text{O}$  and 48-1548 for  $\text{CuO}$ .<sup>31</sup> No diffraction peak of  $\text{TiO}_2$  was obtained for the photocathode because of the low content of the  $\text{TiO}_2$  protective layer.

The Raman spectra shown in Fig. 3(a) further confirmed the formation of the  $\text{BiVO}_4$  photoanode and  $\text{Cu}_2\text{O}$  photocathode. The Raman spectra of the  $\text{BiVO}_4$  nanostructures proved the formation of the monoclinic scheelite  $\text{BiVO}_4$  exhibiting the external mode vibration, symmetric and asymmetric deformation of  $\text{VO}_4^{3-}$  and symmetric stretch mode of V–O at  $207.79\text{ cm}^{-1}$ ,  $324.06\text{ cm}^{-1}$ ,  $369.52\text{ cm}^{-1}$  and  $819.78\text{ cm}^{-1}$ , respectively.<sup>32</sup> The deposition of  $\text{FeOOH}$  and  $\text{NiOOH}$  has no effect on the Raman spectra because of the low content of the dual layer co-catalysts. Similarly, Fig. 3(b) proved the formation of  $\text{Cu}_2\text{O}$  photocathodes and the mixed phase formation of  $\text{Cu}_2\text{O}/\text{CuO}$ . The second order Raman peak of cubic  $\text{Cu}_2\text{O}$  was ascertained by the sharp peak at  $207.05\text{ cm}^{-1}$ . The peak at  $293.96\text{ cm}^{-1}$  confirmed the presence of  $\text{CuO}$  in the  $\text{Cu}_2\text{O}/\text{CuO}$  and  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  photocathodes. The sharp peak at  $207.05\text{ cm}^{-1}$  (peak of  $\text{Cu}_2\text{O}$ ) was absent for the pure  $\text{CuO}$  sample.<sup>33</sup> The significance of the peaks of the  $\text{BiVO}_4$  photoanode and  $\text{Cu}_2\text{O}$  photocathodes are summarized in Table S1 in the ESI.†

Optical absorption properties are essential in understanding the electronic structure of photocatalysts, which further determines the bandgap of materials. In order to evaluate the optoelectronic properties, UV-vis absorption spectra were measured. Fig. 4(a) shows the absorbance spectra of the  $\text{BiVO}_4$  nanostructured photoanode. The absorption edge of the photoanodes started at around  $550\text{ nm}$ . The absorption edge of  $\text{Cu}_2\text{O}$

was observed at around  $700\text{ nm}$ , shown in Fig. 4(c). Upon the formation of  $\text{CuO}$  on  $\text{Cu}_2\text{O}$  after annealing, the formed heterojunction red-shifted the absorption edge to around  $850\text{ nm}$  due to the presence of  $\text{CuO}$  on the top surface. After thermal oxidation, the top surface of the photocathode was changed from reddish yellow to black, which implies the formation of  $\text{CuO}$ . The color of the  $\text{Cu}_2\text{O}$  layer was still visible, when the photocathode was viewed from the back side of the conducting substrate. The bandgap was calculated using the absorption spectra from the Tauc's plot shown in Fig. 4(b) and (d). The values of the absorption edge and the band gap of the  $\text{BiVO}_4$  photoanodes and  $\text{Cu}_2\text{O}$  photocathodes are summarized in Table S2 in the ESI.†

### 3.2 Photoelectrochemical (PEC) properties

The individual PEC performance of the photoelectrodes were analyzed using a three-electrode setup in  $0.1\text{ M Na}_2\text{SO}_4$  electrolyte ( $\text{pH} = 6$ ) under AM 1.5 G illumination, and the results are shown in Fig. 5. From Fig. 5(a), the bare  $\text{BiVO}_4$  nanostructured photoanode provided an anodic response upon illumination, and produced a photocurrent density of  $0.65\text{ mA cm}^{-2}$  at  $1.23\text{ V vs. RHE}$ . The onset potential of the bare  $\text{BiVO}_4$  nanostructure photoanode was  $0.45\text{ V vs. RHE}$ . The  $\text{BiVO}_4/\text{FeOOH}$  and  $\text{BiVO}_4/\text{NiOOH}$  photoanode achieved an improved photocurrent density of  $1.24$  and  $0.91\text{ mA cm}^{-2}$  at  $1.23\text{ V vs. RHE}$ , and exhibited a considerable cathodic shift in the onset potential ( $0.41\text{ V vs. RHE}$ ). The cathodic shift in the onset potential was ascribed to the reduced surface recombination and accelerated oxygen evolution reaction. The result verifies that the  $\text{FeOOH}$  and  $\text{NiOOH}$  co-catalysts effectively collect the

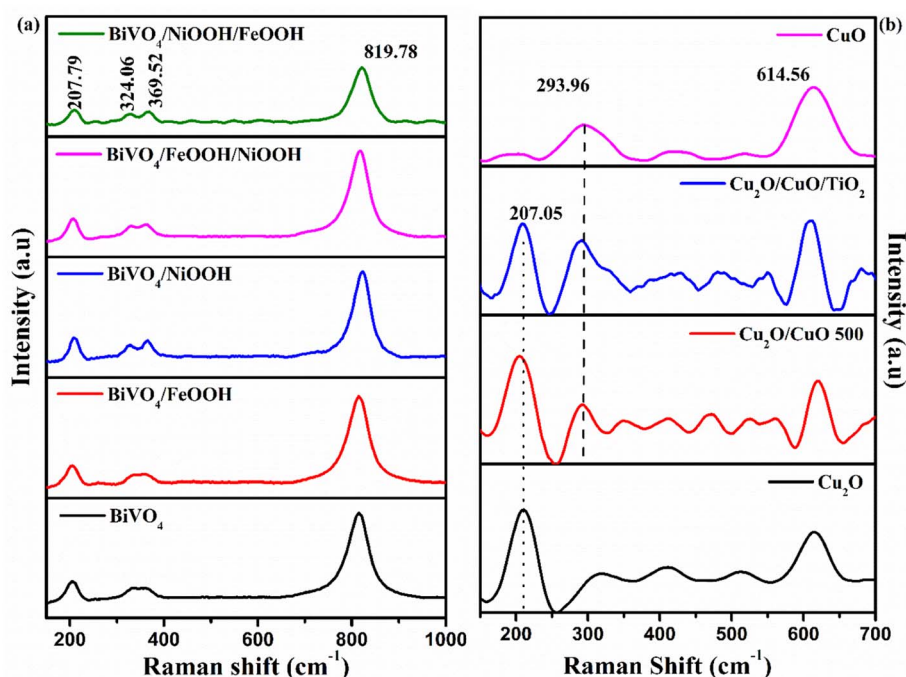


Fig. 3 (a) Raman vibrational spectra of (a)  $\text{BiVO}_4$ ,  $\text{BiVO}_4/\text{FeOOH}$ ,  $\text{BiVO}_4/\text{NiOOH}$ ,  $\text{BiVO}_4/\text{FeOOH}/\text{NiOOH}$  and  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  nanostructured photoanodes and (b)  $\text{Cu}_2\text{O}$ ,  $\text{Cu}_2\text{O}/\text{CuO}$ ,  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  and  $\text{CuO}$  photocathodes.

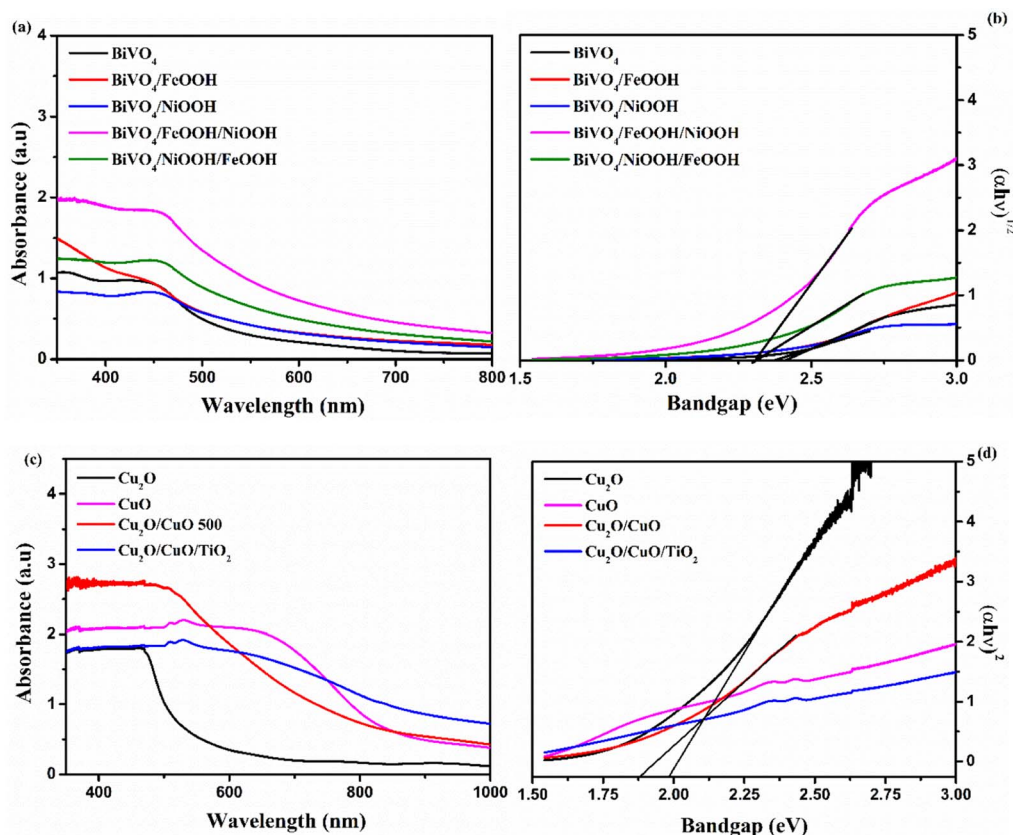


Fig. 4 (a and c) UV-vis absorption spectra. (b and d) Tauc's plot of  $\text{BiVO}_4$ ,  $\text{BiVO}_4/\text{FeOOH}$ ,  $\text{BiVO}_4/\text{NiOOH}$ ,  $\text{BiVO}_4/\text{FeOOH}/\text{NiOOH}$  and  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  nanostructured photoanodes and  $\text{Cu}_2\text{O}$ ,  $\text{Cu}_2\text{O}/\text{CuO}$  (inset)  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  and  $\text{CuO}$  photocathodes.

photogenerated charge carriers for the water oxidation reaction. The combination of both FeOOH and NiOOH co-catalysts on  $\text{BiVO}_4$  significantly boosted the photocurrent density compared to the individual co-catalyst. The significant enhancement in the photocurrent density and the reduction in the onset potential could be due to the synergic effect of the dual layer co-catalyst configuration. The  $\text{BiVO}_4/\text{NiOOH}$  interface minimizes the recombination, while the FeOOH/electrolyte interface enables the surface charge to be more favorable for improving the water oxidation reaction. Chronoamperometry ( $j$  vs.  $t$ ) measurements of the  $\text{BiVO}_4$  nanostructured photoanodes shown in Fig. 5(b) were performed at 1.23 V vs. RHE for 140 seconds, and the illumination was chopped for every 20 seconds. The  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  photoanode produced a stable photocurrent density of  $1.90 \text{ mA cm}^{-2}$  for the entire 140 seconds duration.

The PEC performance of the photocathode is shown in Fig. 5(c). As seen from the figure, all photocathodes produced a cathodic response upon illumination, indicating the intrinsic p-type nature of the photoelectrodes. In our previous works, we chose  $\text{Cu}_2\text{O}$  as photocathodes with protective layers in the tandem structure, which produced a decent photocurrent density.<sup>34,35</sup> In this work, a heterojunction of  $\text{Cu}_2\text{O}/\text{CuO}$  has been chosen with the  $\text{TiO}_2$  protective layer to improve the charge separation and minimize the photocorrosion. The bare  $\text{Cu}_2\text{O}$  and  $\text{CuO}$  photocathode produced photocurrent densities

of  $-0.62$  and  $-0.81 \text{ mA cm}^{-2}$  at 0 V vs. RHE, respectively. On the other hand, the  $\text{Cu}_2\text{O}/\text{CuO}$  thin film heterojunction structure produced an enhanced photocurrent density of  $-1.26 \text{ mA cm}^{-2}$  at 0 V vs. RHE, which is higher than the bare  $\text{Cu}_2\text{O}$  and  $\text{CuO}$  thin films. The results proved that the heterojunction structure helped in facilitating charge separation due to favorable band alignment at the interface of  $\text{Cu}_2\text{O}/\text{CuO}$  and electrolyte. As a result, an improved photocurrent was achieved for this structure. The heterojunction structure was further protected with a thin  $\text{TiO}_2$  layer, and the representative  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  thin film photocathode achieved the highest photocurrent density of  $-1.61 \text{ mA cm}^{-2}$  at 0 V vs. RHE among all prepared photocathodes. The increased onset potential and enhanced photocurrent density were attributed to protection of  $\text{TiO}_2$  and the charge separation by the heterojunction structure. The  $j$  vs.  $t$  measurement of the  $\text{Cu}_2\text{O}$  photocathode was performed at 0 V vs. RHE for 140 seconds, as shown in Fig. 5(d). It is clearly visible that the  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  photocathode produced a stable current density of  $1.60 \text{ mA cm}^{-2}$  for the entire measurement duration. Table 1 presents the summarized PEC results of the photoelectrodes.

The photostability of the  $\text{BiVO}_4$  vs.  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  photoanode and  $\text{Cu}_2\text{O}$  vs.  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  photocathode was measured at 1.23 V vs. RHE and 0 V vs. RHE, respectively, for 2000 seconds. From Fig. S5 (a),† it was observed that the addition of the dual-layered electrocatalyst produced a stable





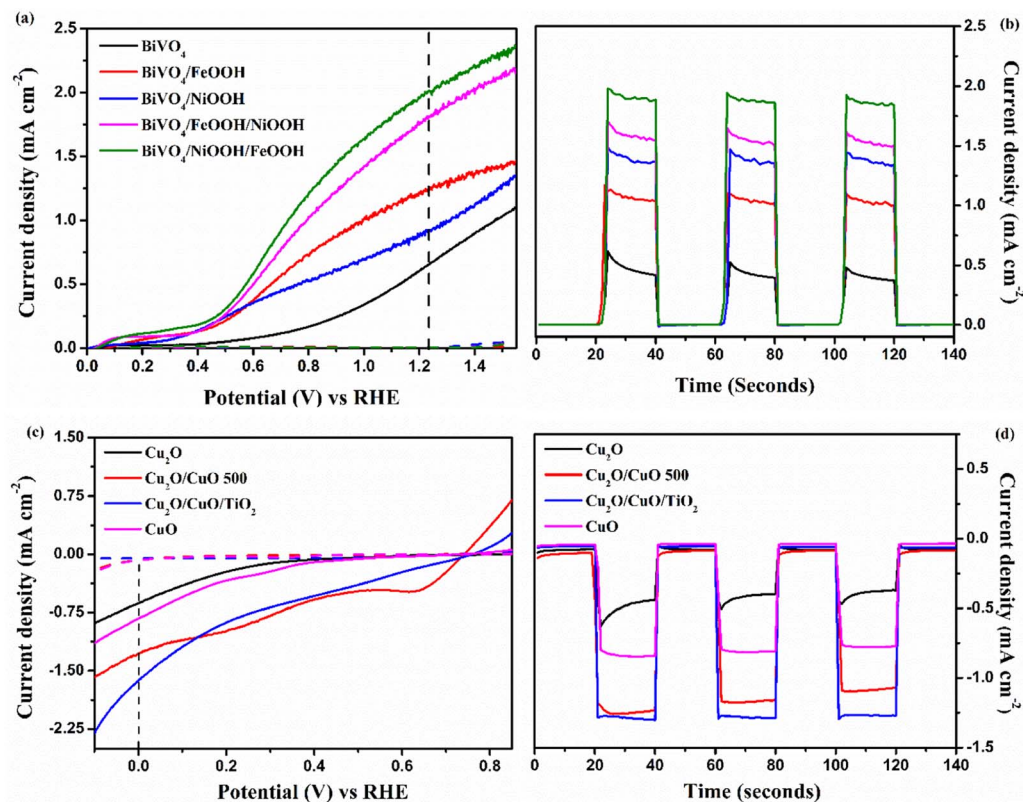


Fig. 5 (a and c) Linear sweep voltammetry (LSV) response of BiVO<sub>4</sub>, BiVO<sub>4</sub>/FeOOH, BiVO<sub>4</sub>/NiOOH, BiVO<sub>4</sub>/FeOOH/NiOOH and BiVO<sub>4</sub>/NiOOH/FeOOH photoanodes and Cu<sub>2</sub>O, Cu<sub>2</sub>O/CuO, Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> and CuO photocathodes. (b and d) Chronoamperometry (*j* vs. *t*) measurements performed at 1.23 V vs. RHE for the BiVO<sub>4</sub> photoanodes and 0 V vs. RHE for the Cu<sub>2</sub>O photocathodes tested in 0.1 M Na<sub>2</sub>SO<sub>4</sub> (pH 6) in AM 1.5 G equipped illumination source with a power intensity of 100 mW cm<sup>-2</sup>.

current density of  $\sim 2 \text{ mA cm}^{-2}$  throughout the test without any significant degradation. Similarly, the Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> photocathode was stable throughout the measurement and retained the current density of  $-1.59 \text{ mA cm}^{-2}$ . On the other hand, the bare Cu<sub>2</sub>O photocathode was unstable in the photostability measurement test, as shown in Fig. S5(b).†

To further understand the kinetics of the PEC water splitting and the performance of the photoelectrodes, an

electrochemical impedance spectroscopy (EIS) analysis was performed in a three-electrode configuration under illumination. The EIS analysis in Fig. 6 is shown in the form of a Nyquist plot from which the equivalent circuit can be constructed, which provides insights into the electrode and electrolyte interface. The Randles–Ershel fitting model was used in this study in which  $R_s$  is the series resistance,  $C_{PE}$  is the constant phase element accounted for the capacitance of the Helmholtz

Table 1 Tabulation of the PEC parameters of BiVO<sub>4</sub> photoanodes and Cu<sub>2</sub>O photocathodes

| Photoanode                             | Current density at 1.23 V vs. RHE (mA cm <sup>-2</sup> ) | Onset potential (V vs. RHE) | Charge transfer resistance $R_{ct}$ (Ω) |
|--|--|-----------------------------|---|
| BiVO <sub>4</sub>                      | 0.65 mA cm <sup>-2</sup>                                 | 0.46 V                      | 1531 Ω                                  |
| BiVO <sub>4</sub> /FeOOH               | 1.24 mA cm <sup>-2</sup>                                 | 0.43 V                      | 1115 Ω                                  |
| BiVO <sub>4</sub> /NiOOH               | 0.91 mA cm <sup>-2</sup>                                 | 0.42 V                      | 1032 Ω                                  |
| BiVO <sub>4</sub> /FeOOH/NiOOH         | 1.81 mA cm <sup>-2</sup>                                 | 0.45 V                      | 876.9 Ω                                 |
| BiVO <sub>4</sub> /NiOOH/FeOOH         | 2.05 mA cm <sup>-2</sup>                                 | 0.40 V                      | 627 Ω                                   |
| Photocathode                           | Current density at 0 V vs. RHE (mA cm <sup>-2</sup> )    | Onset potential (V vs. RHE) | Charge transfer resistance $R_{ct}$ (Ω) |
| Cu <sub>2</sub> O                      | $-0.62 \text{ mA cm}^{-2}$                               | 0.37 V                      | 1280 Ω                                  |
| CuO                                    | $-0.81 \text{ mA cm}^{-2}$                               | 0.44 V                      | 935.8 Ω                                 |
| Cu <sub>2</sub> O/CuO                  | $-1.26 \text{ mA cm}^{-2}$                               | 0.73 V                      | 848.5 Ω                                 |
| Cu <sub>2</sub> O/CuO/TiO <sub>2</sub> | $-1.61 \text{ mA cm}^{-2}$                               | 0.75 V                      | 407.5 Ω                                 |

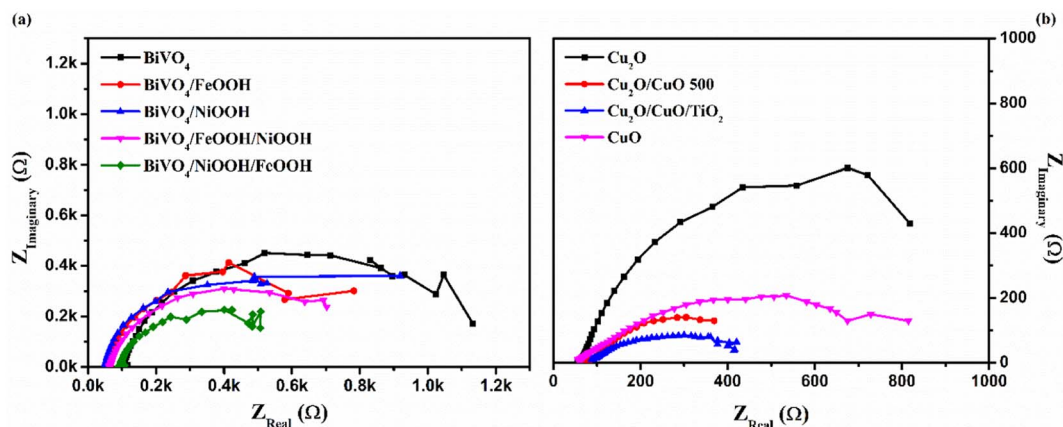


Fig. 6 Electrochemical impedance spectra (EIS) of (a)  $\text{BiVO}_4$ ,  $\text{BiVO}_4/\text{FeOOH}$ ,  $\text{BiVO}_4/\text{NiOOH}$ ,  $\text{BiVO}_4/\text{FeOOH}/\text{NiOOH}$  and  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  photoanodes and (b)  $\text{Cu}_2\text{O}$ ,  $\text{Cu}_2\text{O}/\text{CuO}$ ,  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  and  $\text{CuO}$  photocathodes tested in 0.1 M  $\text{Na}_2\text{SO}_4$  (pH 6) in AM 1.5 G equipped illumination source with a power intensity of  $100 \text{ mW cm}^{-2}$ .

layer from the electrode and electrolyte interface, and  $R_{\text{ct}}$  is the charge transfer resistance across the interface.

Fig. 6(a) shows the EIS plot of  $\text{BiVO}_4$  and co-catalyst-loaded  $\text{BiVO}_4$  nanostructured photoanodes measured at 1.23 V vs. RHE. In the EIS spectra, the smaller semicircle corresponds to  $R_s$  and the larger semicircle corresponds to  $R_{\text{ct}}$ . Upon addition of the co-catalysts, a significant reduction in the charge transfer resistance was observed. The smaller  $R_{\text{ct}}$  value signifies an efficient charge transfer between the semiconductor–electrolyte interfaces. It was also observed that  $R_{\text{ct}}$  further decreases for the dual-cocatalyst loaded  $\text{BiVO}_4$  nanostructured photoanode, compared to the mono co-catalyst counterpart. The  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  photoanode exhibited the  $R_{\text{ct}}$  value of 627  $\Omega$ , which is lower than that for the bare  $\text{BiVO}_4$  (1531  $\Omega$ ). The result proved that the first layer co-catalyst aids in minimizing the surface defects and recombination, and the second layer co-catalyst helps in boosting the kinetics of OER. On the other hand, the EIS spectra of  $\text{Cu}_2\text{O}$  and the  $\text{Cu}_2\text{O}$ -modified photocathodes are shown in Fig. 6(b), which was measured at 0 V vs. RHE. The value of  $R_{\text{ct}}$  decreased in the order of  $\text{Cu}_2\text{O} > \text{CuO} > \text{Cu}_2\text{O}/\text{CuO} > \text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$ . The extracted EIS spectra values

also support the photocurrent density values observed from the LSV response. The  $\text{TiO}_2$ -protected  $\text{Cu}_2\text{O}/\text{CuO}$  photocathode has the lowest charge transfer resistance of 407.5  $\Omega$ , which is lower than that of the bare  $\text{Cu}_2\text{O}$  (1280  $\Omega$ ). The constructed equivalent circuit of the photoanode and photocathode is shown in Fig. S4 in the ESI.†

Furthermore, Mott–Schottky (MS) analysis was carried for  $\text{BiVO}_4$  and  $\text{Cu}_2\text{O}$  photoelectrodes under dark condition at 1 kHz frequency. The MS plots are used to calculate the flat band potential ( $E_{\text{FB}}$ ) and carrier density. Fig. 7(a) shows the MS plots of the  $\text{BiVO}_4$  nanostructured photoanodes, which exhibit positive slopes, indicating the intrinsic nature of the n-type behavior. The  $E_{\text{FB}}$  value of the bare  $\text{BiVO}_4$  and  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  photoanode was estimated to be 0.40 V and 0.41 V vs. RHE, respectively. The cathodic shift of  $E_{\text{FB}}$  for the latter is correlated to the significant reduction in the overpotential of OER caused by the  $\text{FeOOH}$  and  $\text{NiOOH}$  co-catalysts. The carrier density was extracted using the slope of the obtained MS plots and the values are summarized in Table 2. The higher carrier concentration means the photoanode/photocathode requires a low overpotential to initiate the charge transfer reaction,

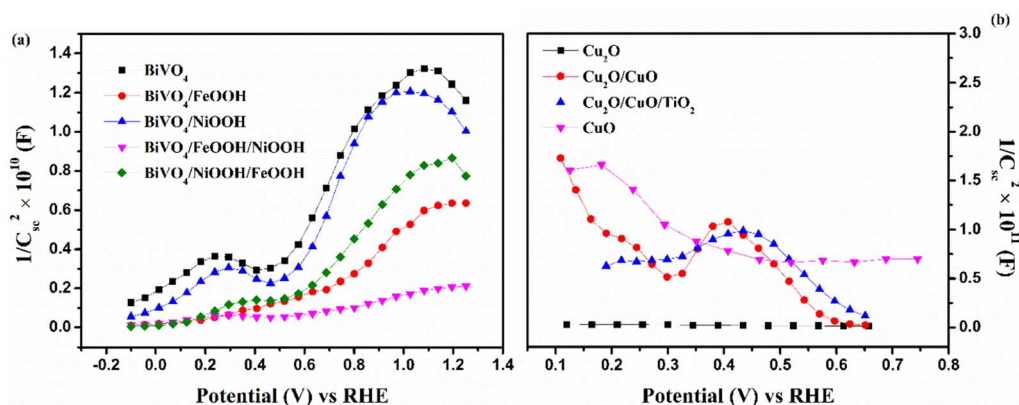


Fig. 7 Mott–Schottky plots of (a)  $\text{BiVO}_4$ ,  $\text{BiVO}_4/\text{FeOOH}$ ,  $\text{BiVO}_4/\text{NiOOH}$ ,  $\text{BiVO}_4/\text{FeOOH}/\text{NiOOH}$  and  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  photoanodes and (b)  $\text{Cu}_2\text{O}$ ,  $\text{Cu}_2\text{O}/\text{CuO}$ ,  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  and  $\text{CuO}$  photocathodes tested in 0.1 M  $\text{Na}_2\text{SO}_4$  (pH 6) at 1 kHz under dark conditions.





**Table 2** Tabulation of the PEC parameters of BiVO<sub>4</sub> photoanodes and Cu<sub>2</sub>O photocathode

| Photoanode                     | Flat band potential ( $E_{\text{FB}}$ ) (V vs. RHE) | Carrier density ( $\text{cm}^{-3}$ ) |
|--------------------------------|---|--------------------------------------|
| BiVO <sub>4</sub>              | 0.40 V  | $6.129 \times 10^{20}$               |
| BiVO <sub>4</sub> /FeOOH       | 0.44 V  | $1.327 \times 10^{21}$               |
| BiVO <sub>4</sub> /NiOOH       | 0.43 V  | $5.249 \times 10^{21}$               |
| BiVO <sub>4</sub> /FeOOH/NiOOH | 0.42 V  | $6.025 \times 10^{21}$               |
| BiVO <sub>4</sub> /NiOOH/FeOOH | 0.41 V  | $8.561 \times 10^{21}$               |

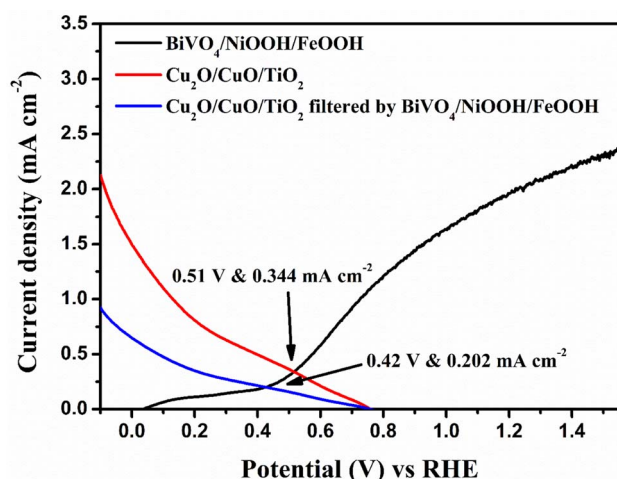
  

| Photocathode                           | Flat band potential ( $E_{\text{FB}}$ ) (V vs. RHE) | Carrier density ( $\text{cm}^{-3}$ ) |
|--|---|--------------------------------------|
| Cu <sub>2</sub> O                      | 0.51 V  | $-1.218 \times 10^{20}$              |
| CuO                                    | 0.57 V  | $-1.067 \times 10^{20}$              |
| Cu <sub>2</sub> O/CuO                  | 0.62 V  | $-3.129 \times 10^{20}$              |
| Cu <sub>2</sub> O/CuO/TiO <sub>2</sub> | 0.64 V  | $-8.122 \times 10^{20}$              |

which is evident from the low charge transfer resistance obtained in the EIS spectra and the highest current density of the BiVO<sub>4</sub>/NiOOH/FeOOH photoanode and Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> photocathode obtained in the LSV spectra. Fig. 7(b) shows the MS plot of the Cu<sub>2</sub>O photocathodes, which shows the typical p-type behavior manifested as the negative slope. The MS result of the bare Cu<sub>2</sub>O yielded the  $E_{\text{FB}}$  value of 0.51 V vs. RHE. The  $E_{\text{FB}}$  of 0.64 V vs. RHE was obtained for the Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> photocathode, which is more anodic than the bare Cu<sub>2</sub>O, implying the potential of the heterojunction and protective layer in minimizing the surface defects.

### 3.3 Tandem PEC cell analysis

In order to analyze the viability of the proposed tandem cell, the absolute LSV responses of the BiVO<sub>4</sub> photoanodes and Cu<sub>2</sub>O photocathodes are plotted to find the intersecting point, which provides the operating voltage and current density based on the



**Fig. 8** Overlay of the absolute LSV responses of BiVO<sub>4</sub>, BiVO<sub>4</sub>/NiOOH/FeOOH, Cu<sub>2</sub>O and Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> to find the operating point of the tandem cell.

PEC activity of the individual photoelectrodes. Fig. 8 shows the overlay plot of the absolute LSV responses of the BiVO<sub>4</sub>/NiOOH/FeOOH vs. Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> tandem PEC cells. The overlay curve provided the operating photocurrent density of 0.344 mA cm<sup>-2</sup> at the operating voltage of 0.51 V vs. RHE for the BiVO<sub>4</sub>/NiOOH/FeOOH vs. Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> tandem cell. In the tandem cell measurement, the photoanode was placed on top of the photocathode for which a slight reduction in the operating current was identified as 0.202 mA cm<sup>-2</sup> at 0.42 V vs. RHE for BiVO<sub>4</sub>/NiOOH/FeOOH filtered with the Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> tandem cell. The tabulation of the operating points of the constructed tandem cell is provided in Table S3 in the ESI.† This intersection point provides us with the actual maximum limit of the proposed tandem PEC cell. The non-zero operating current density hints at the possibility of unassisted operation of the tandem PEC cell. The calculated solar-to-hydrogen (STH) conversion efficiency for the BiVO<sub>4</sub>/NiOOH/FeOOH–Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> tandem cell was 0.27% using eqn (1.1) in the ESI.†

The tandem cell was constructed using BiVO<sub>4</sub> as the top and Cu<sub>2</sub>O as the bottom, as shown in Fig. S6 in the ESI.† We compared the performance of BiVO<sub>4</sub> vs. Cu<sub>2</sub>O and BiVO<sub>4</sub>/NiOOH/FeOOH vs. Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> tandem cells using two-electrode LSV analysis. Fig. 9(a) shows the LSV response under the AM1.5 G equipped illumination source with a power intensity of 100 mW cm<sup>-2</sup>. The representative BiVO<sub>4</sub>/NiOOH/FeOOH vs. Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> tandem cell produced an unassisted photocurrent density of 0.201 mA cm<sup>-2</sup> at zero bias, whereas the bare BiVO<sub>4</sub> vs. Cu<sub>2</sub>O produced a photocurrent density of 25.4 μA cm<sup>-2</sup> at zero bias. The result suggested the potential of the co-catalyst loading in the photoanode side and heterojunction formation in the photocathode side upon enhancement of the PEC performance. Finally, the unassisted photostability tests were performed for both tandem cell structures for 3000 seconds, as shown in Fig. 9(b). The bare tandem cells provided negligible current density under illumination. This is due to the sluggish water splitting reaction kinetics and photocorrosion of the photocathode. For the BiVO<sub>4</sub>/NiOOH/FeOOH vs. Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> tandem cell, the current density spiked to 0.32 mA cm<sup>-2</sup> and the current density became constant after 50 seconds, with a stable current density of 0.187 mA cm<sup>-2</sup>. The synergic effect of NiOOH/FeOOH on lowering the overpotential of the BiVO<sub>4</sub> nanostructure and the double protection of Cu<sub>2</sub>O by CuO/TiO<sub>2</sub> enhanced the unassisted current density and ensured the stable operation of the tandem cell. The comparison of the tandem PEC cell with our previous works and the recent literature are tabulated in Table 3.

### 3.4 Post-PEC test characterization

XRD patterns of the photoanode and photocathode after the PEC test are shown in Fig. 10. The XRD patterns were recorded after the tandem PEC cell measurements, such as LSV and stability test. The XRD patterns of the BiVO<sub>4</sub>/NiOOH/FeOOH photoanode were well indexed with JCPDS card no. 014-06888, as shown in Fig. 10(a), both before and after the PEC test. No shift in the peaks or appearance of new peaks was found for the



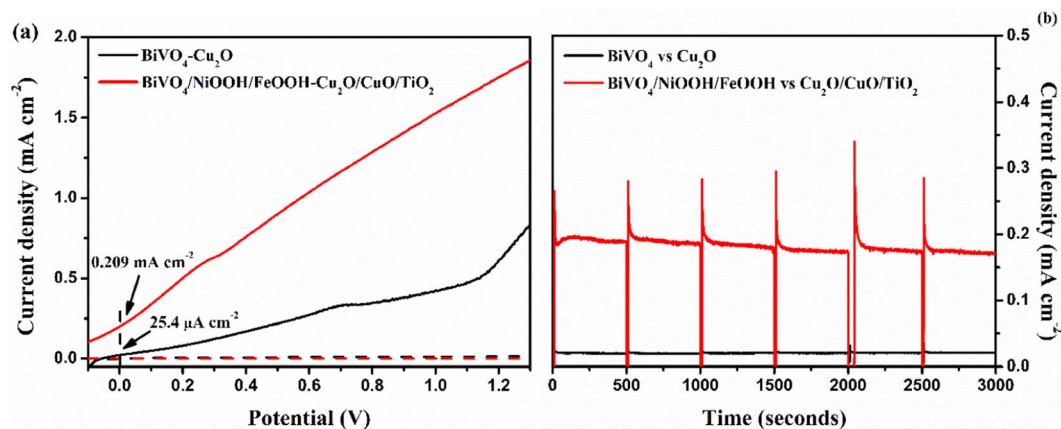


Fig. 9 (a) Two-electrode LSV responses, (b) stability tests ( $j$  vs.  $t$ ) of  $\text{BiVO}_4$  vs.  $\text{Cu}_2\text{O}$  and  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  vs.  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  tandem cell tested in 0.1 M  $\text{Na}_2\text{SO}_4$  (pH 6) in AM 1.5 G equipped illumination source with a power intensity of  $100 \text{ mW cm}^{-2}$ . The chopping of light was carried out every 500 seconds.

photoanode after the PEC tests, demonstrating the high stability of the  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  photoanode. There was only a minor decrease in the intensity of the XRD pattern obtained after PEC testing, which could be due to different amounts used in the sample preparation. Similarly, the XRD patterns of the  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  photocathode obtained before

and after PEC measurements are shown in Fig. 10(b). There is no significant change in the XRD peak positions and no new peaks appeared after the PEC test, which implied the stable nature of the photocathodes as a result of the  $\text{CuO}$  and  $\text{TiO}_2$  protective layers.

Table 3 PEC performance comparison of various similar tandem PEC cells reported in the literature

| Photoanode                                    | Photocathode  | Electrolyte   | pH  | Current density of the tandem cell | References |
|---|---|---|-----|------------------------------------|------------|
| $\text{BiVO}_4/\text{Co-Pi}$                  | $\text{Cu}_2\text{O}/\text{Al:ZnO}/\text{TiO}_2/\text{RuO}_x$     | 0.5 M $\text{Na}_2\text{SO}_4$ + 0.09 $\text{KH}_2\text{PO}_4$ + $\text{K}_2\text{HPO}_4$ | 6   | $0.25 \text{ mA cm}^{-2}$          | 36         |
| $\text{BiVO}_4/\text{TiO}_2/\text{FeOOH}$     | $\text{Cu}_2\text{O}$   | 0.2 M phosphate buffer  | 8   | $0.12 \text{ mA cm}^{-2}$          | 24         |
| W- $\text{BiVO}_4/\text{Co-Pi}$               | $\text{CuBi}_2\text{O}_4/\text{CdS}/\text{TiO}_2/\text{RuO}_x$    | 0.3 M $\text{K}_2\text{SO}_4$ + 0.2 M phosphate buffer                                    | 6.8 | $0.1 \text{ mA cm}^{-2}$           | 37         |
| $\text{BiVO}_4/\text{Co-Bi}$                  | $\text{CuBi}_2\text{O}_4/\text{Co-Bi}$                            | 0.5 M borate buffer   | 9.2 | $0.036 \text{ mA cm}^{-2}$         | 38         |
| $\text{BiVO}_4$                               | $\text{Au}/\text{Cu}_2\text{O}/\text{H:Tl}_3\text{C}_3\text{T}_x$ | 1 M $\text{Na}_2\text{SO}_4$  | 5   | $-0.45 \text{ mA cm}^{-2}$         | 39         |
| Mo- $\text{BiVO}_4/\text{Co-Pi}$              | $\text{CuBi}_2\text{O}_4/\text{Pt}$                               | 0.1 M potassium phosphate buffer  | 7   | $0.15 \text{ mA cm}^{-2}$          | 40         |
| Mo- $\text{BiVO}_4/\text{TiO}_2/\text{FeOOH}$ | $\text{Cu}_2\text{O}/\text{TiO}_2/\text{MoS}_2$                   | 0.1 M $\text{Na}_2\text{SO}_4$  | 6   | $0.0653 \text{ mA cm}^{-2}$        | 34         |
| Mo- $\text{BiVO}_4/\text{C}/\text{FeOOH}$     | $\text{Cu}_2\text{O}/\text{C}/\text{MoS}_2$                       | 0.1 M $\text{Na}_2\text{SO}_4$  | 6   | $0.107 \text{ mA cm}^{-2}$         | 35         |
| $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$     | $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$                     | 0.1 M $\text{Na}_2\text{SO}_4$  | 6   | $0.187 \text{ mA cm}^{-2}$         | This work  |

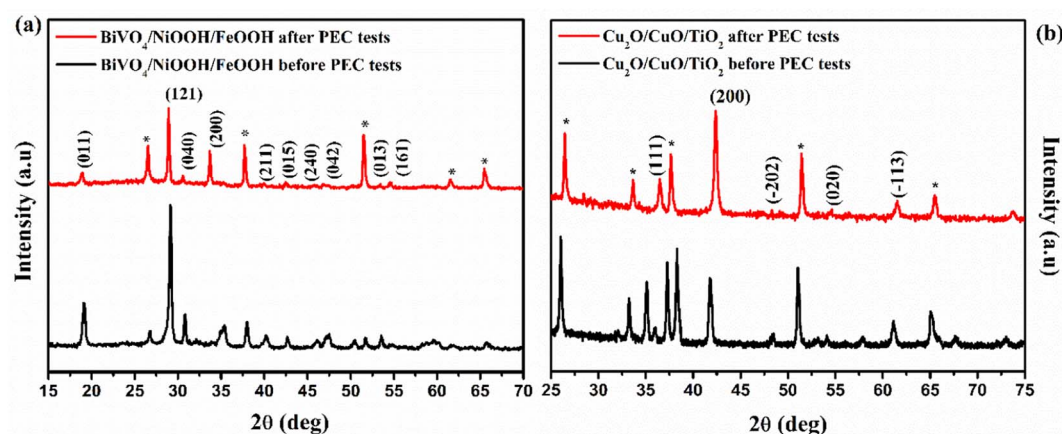


Fig. 10 XRD pattern obtained before and after PEC measurements of the (a)  $\text{BiVO}_4/\text{NiOOH}/\text{FeOOH}$  photoanode and (b)  $\text{Cu}_2\text{O}/\text{CuO}/\text{TiO}_2$  photocathode.



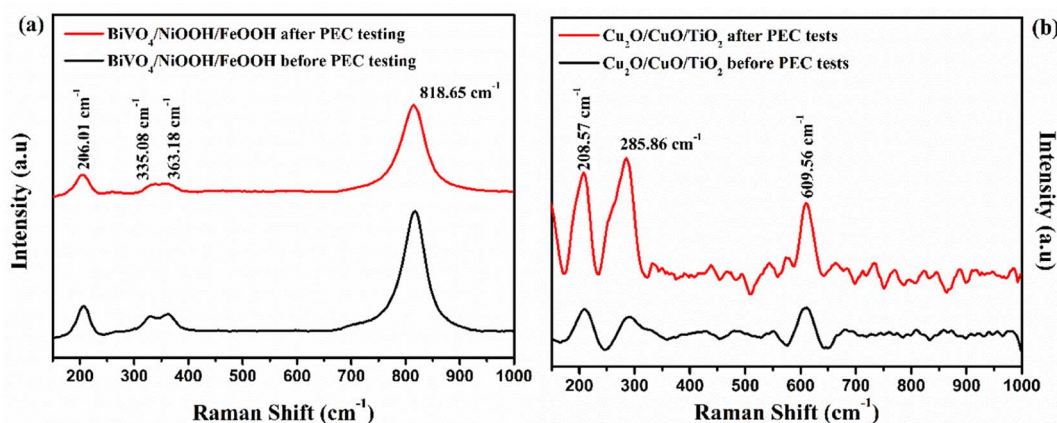


Fig. 11 Raman spectra obtained before and after PEC testing of (a) the BiVO<sub>4</sub>/NiOOH/FeOOH photoanode and (b) Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> photocathode.

Raman spectra were obtained for the BiVO<sub>4</sub>/NiOOH/FeOOH photoanode and Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> photocathodes, and are illustrated in Fig. 11(a) and (b), respectively. The Raman spectra of the photoanode showed that no significant change in peak position or appearance of new peaks occurred after PEC measurement. Similarly, in the Raman spectra of the photocathode before and after PEC testing, the photocathode exhibited two major characteristic peaks of Cu<sub>2</sub>O and CuO at 208.57 cm<sup>-1</sup> and 285.86 cm<sup>-1</sup>, respectively. The major peak at 208.57 cm<sup>-1</sup> was the characteristic second order Raman peak of cubic Cu<sub>2</sub>O, and the peak at 285.86 cm<sup>-1</sup> was the characteristic peak of CuO. The Raman result also confirmed the stable nature of the photoelectrodes after the PEC tests.

## 4. Conclusion

A simple and economical strategy for boosting the PEC performance of the BiVO<sub>4</sub> and Cu<sub>2</sub>O tandem cell was reported. The tandem cell consisted of the nanostructured BiVO<sub>4</sub>/NiOOH/FeOOH photoanode and heterojunction Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> photocathode, which exhibited improved PEC performance compared to reference tandem structures with single component counterparts. The formation of the BiVO<sub>4</sub> nanostructures increased the surface active area. The co-catalyst NiOOH facilitated the separation of charge carriers from BiVO<sub>4</sub>, and FeOOH facilitated the transfer of charge carriers to the surface of the photoelectrode. The representative photoanode and photocathode produced a photocurrent density of 2.05 mA cm<sup>-2</sup> at 1.23 V vs. RHE and 1.61 mA cm<sup>-2</sup> at 0 V vs. RHE, respectively. The thermal oxidation of Cu<sub>2</sub>O *in situ* formed a Cu<sub>2</sub>O/CuO heterojunction, which efficiently separated the photo-generated charges due to favorable downward band bending. The BiVO<sub>4</sub>/NiOOH/FeOOH vs. Cu<sub>2</sub>O/CuO/TiO<sub>2</sub> model tandem cell produced an unassisted current density of 0.185 mA cm<sup>-2</sup>, which is equivalent to 0.22% STH efficiency. The tandem cell was stable during the testing duration of 3000 second, and the post-XRD and Raman characterizations showed negligible structural changes in the photoelectrodes.

## Author contributions

Sitaaraman S. R.: methodology, writing – original draft. Nirmala Grace A.: funding acquisition, validation. Jiefang Zhu: revising draft, validation. Raja Sellappan: methodology, writing – original draft, funding acquisition, validation.

## Conflicts of interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

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## References

- 1 A. Fujishima and K. Honda, *Nature*, 1972, **238**, 37–38.
- 2 P. Chatterjee, M. S. K. Ambati, A. K. Chakraborty, S. Chakraborty, S. Biring, S. Ramakrishna, T. K. S. Wong, A. Kumar, R. Lawaniya and G. K. Dalapati, *Energy Convers. Manag.*, 2022, **261**, 115648.
- 3 B. D. Sherman, M. V. Sheridan, K. R. Wee, S. L. Marquard, D. Wang, L. Alibabaei, D. L. Ashford and T. J. Meyer, *J. Am. Chem. Soc.*, 2016, **138**, 16745–16753.
- 4 Gurudayal, D. Sabba, M. H. Kumar, L. H. Wong, J. Barber, M. Grätzel and N. Mathews, *Nano Lett.*, 2015, **15**, 3833–3839.
- 5 A. M. K. Fehr, A. Agrawal, F. Mandani, C. L. Conrad, Q. Jiang, S. Y. Park, O. Alley, B. Li, S. Sidhik, I. Metcalf, C. Botello, J. L. Young, J. Even, J. C. Blancon, T. G. Deutsch, K. Zhu, S. Albrecht, F. M. Toma, M. Wong and A. D. Mohite, *Nat. Commun.*, 2023, **14**, 1–12.
- 6 Q. Chen, G. Fan, H. Fu, Z. Li and Z. Zou, *Adv. Phys.: X*, 2018, **3**, 863–884.





- 7 M. S. Prévot and K. Sivula, *J. Phys. Chem. C*, 2013, **117**, 17879–17893.
- 8 C. Jiang, S. J. A. Moniz, A. Wang, T. Zhang and J. Tang, *Chem. Soc. Rev.*, 2017, **46**, 4645–4660.
- 9 K. Zhang, M. Ma, P. Li, D. H. Wang and J. H. Park, *Adv. Energy Mater.*, 2016, **6**, 1600602.
- 10 Y. Liu, W. Qiu, G. He, K. Wang, Y. Wang, L. Chen, Q. Wu, W. Li and J. Li, *J. Phys. Chem. C*, 2022, **126**, 15596–15605.
- 11 L. Wang, Z. Liu, X. Xu, Y. Jia, Q. Mei, F. Ding, J. Peng and Q. Wang, *ACS Appl. Energy Mater.*, 2022, **5**, 6383–6392.
- 12 K. Chen, R. Wang, Q. Mei, F. Ding, H. Liu, G. Yang, B. Bai and Q. Wang, *Applied Catalysis B: Environment and Energy*, 2024, **344**, 123670.
- 13 J. Zhang, X. Wei, J. Zhao, Y. Zhang, L. Wang, J. Huang and H. She, *Chem. Eng. J.*, 2023, **454**, 140081.
- 14 X. Wei, J. Zhang, L. Wang, Y. Bai, J. Huang, H. She and Q. Wang, *Chem. Eng. J.*, 2024, **482**, 149114.
- 15 S. Majumder, N. D. Quang, T. T. Hien, N. D. Chinh, N. M. Hung, H. Yang, C. Kim and D. Kim, *Appl. Surf. Sci.*, 2021, **546**, 149033.
- 16 S. S. Kalanur and H. Seo, *J. Catal.*, 2022, **410**, 144–155.
- 17 Y. Liu, B. R. Wygant, O. Mabayoje, J. Lin, K. Kawashima, J. H. Kim, W. Li, J. Li and C. Buddie Mullins, *ACS Appl. Mater. Interfaces*, 2018, **10**, 12639–12650.
- 18 D. K. Lee and K. S. Choi, *Nat. Energy*, 2018, **3**, 53–60.
- 19 D. Jeong, W. Jo, J. Jeong, T. Kim, S. Han, M. K. Son and H. Jung, *RSC Adv.*, 2022, **12**, 2632–2640.
- 20 Y. Yang, D. Xu, Q. Wu and P. Diao, *Sci. Rep.*, 2016, **6**, 35138.
- 21 P. Wang, Z. Liu, C. Han, X. Ma, Z. Tong and B. Tan, *J. Nanopart. Res.*, 2021, **23**, 268.
- 22 C. Y. Toe, J. Scott, R. Amal and Y. H. Ng, *J. Photochem. Photobiol., C*, 2019, **40**, 191–211.
- 23 Y. Wang, S. Cao, Y. Huan, T. Nie, Z. Ji, Z. Bai, X. Cheng, J. Xi and X. Yan, *Appl. Surf. Sci.*, 2020, **526**, 146700.
- 24 X. Yin, Q. Liu, Y. Yang, Y. Liu, K. Wang, Y. Li, D. Li, X. Qiu, W. Li and J. Li, *Int. J. Hydrogen Energy*, 2019, **44**, 594–604.
- 25 W. Zhang, J. Ma, L. Xiong, H. Y. Jiang and J. Tang, *ACS Appl. Energy Mater.*, 2020, **3**, 5927–5936.
- 26 J. Wei, C. Zhou, Y. Xin, X. Li, L. Zhao and Z. Liu, *New J. Chem.*, 2018, **42**, 19415–19422.
- 27 I. R. Hamdani and A. N. Bhaskarwar, *Sol. Energy Mater. Sol. Cells*, 2022, **240**, 111719.
- 28 P. P. Kunturu and J. Huskens, *ACS Appl. Energy Mater.*, 2019, **2**, 7850–7860.
- 29 X. Deng, G. C. Wilkes, A. Z. Chen, N. S. Prasad, M. C. Gupta and J. J. Choi, *J. Phys. Chem. Lett.*, 2017, **8**, 3206–3210.
- 30 H. Luo, C. Liu, Y. Xu, C. Zhang, W. Wang and Z. Chen, *Int. J. Hydrogen Energy*, 2019, **44**, 30160–30170.
- 31 H. L. S. Santos, P. G. Corradini, M. A. S. Andrade and L. H. Mascaro, *J. Solid State Electrochem.*, 2020, **24**, 1899–1908.
- 32 A. Galembeck and O. L. Alves, *Thin Solid Films*, 2000, **365**, 90–93.
- 33 M. Balık, V. Bulut and I. Y. Erdogan, *Int. J. Hydrogen Energy*, 2019, **44**, 18744–18755.
- 34 S. R. Sitaaraman, A. Nirmala Grace and R. Sellappan, *RSC Adv.*, 2022, **12**, 31380–31391.
- 35 S. Srinivasa, R. Raghavan, N. G. Andrews and R. Sellappan, *Catalysts*, 2023, **13**, 1–15.
- 36 P. Bornoz, F. F. Abdi, S. D. Tilley, B. Dam, R. Van De Krol, M. Graetzel and K. Sivula, *J. Phys. Chem. C*, 2014, **118**, 16959–16966.
- 37 A. Song, P. Bogdanoff, A. Esau, I. Y. Ahmet, I. Levine, T. Dittrich, T. Unold, R. Van De Krol and S. P. Berglund, *ACS Appl. Mater. Interfaces*, 2020, **12**, 13959–13970.
- 38 Y. H. Lai, K. C. Lin, C. Y. Yen and B. J. Jiang, *Faraday Discuss.*, 2019, **215**, 297–312.
- 39 X. Fu, H. Chang, Z. Shang, P. Liu, J. Liu and H. Luo, *Chem. Eng. J.*, 2020, **381**, 122001.
- 40 J. H. Kim, A. Adishev, J. Kim, Y. S. Kim, S. Cho and J. S. Lee, *ACS Appl. Energy Mater.*, 2018, **1**, 6694–6699.

